NSN 5962-01-105-3658

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View Online at https://aerobasegroup.com/nsn/5962-01-105-3658

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches and 0.310 inches	
Body Height:	
Between 0.140 inches and 0.185 inches	
Maximum Power Dissipation Rating:	
715.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
Radar set, type an/fps-115	
Features Provided:	
Hermetically sealed and monolithic and negative outputs and positive outputs and w/enable and	w/buffered output and w/decoded output
and programmable and 3-state output	
nclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
nput Circuit Pattern:	
10 input	
Case Outline Source And Designator:	
D-2 mil-m-38510	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
5.5 volts power source	
Time Rating Per Chacteristic:	
e 85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds pr	ropagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
49956-952369 drawing (this is the basic governing drawing, such as a contractor drawing, origin	nal equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic government.	
Terminal Type And Quantity:	
16 printed circuit	

Shelf Life:

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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